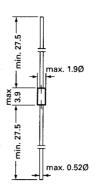
DIACS

DB-3 SILICON BIDIRECTIONAL DIAC

The glass passivated, three-layer, two terminal, axial lead, hermetically sealed diacs are designed specifically for triggering thyristors.

They demonstrate low breakover current at breakover voltage as they withstand peak pulse current. The breakover symmetry is within four volts with a typical breakover voltage

These diacs are intended for use in thyristor phase control, circuits for lamp-dimming, universal-motor speed controls, and heat controls.



Glass case JEDEC DO-35

Dimensions in mm

Semtech's DB-3 is a bi-directional trigger diode designed to operate in conjunction with all of Semtech Electronics' Triacs and SCR's

Storage Temperature

$$T_{STG}$$
 - 40 °C to + 150 °C
 T_{J} - 40 °C to + 100 °C

Operating Temperture

MAXIMUM RATINGS AT 50 °C Ambient

Peak Current (10 μ sec duration, 120 cycle repetition rate) I_n ± 2 Amperes Max.

Peak output voltage e 3 ± volts Max.*

CHARACTERISTICS at 25 °C Ambient

Test	Symbol	Min.	Тур.	Max.	Units
Breakover Voltage	V _{(BR)1} and V _{(BR)2}	28	32	36	Volts
Breakover Currents	$I_{(BR)1}$ and $I_{(BR)2}$	-	-	200	μ amp
Breakover Voltage Symmetry	[V _{(BR)1}] - [V _{(BR)2}]	-	-	3.8	Volts
Dynamic Breakover Voltage Δ I = [I _{BR} to I _F = 10mA]	IΔV±I	5	-	-	Volts
Thermal Impedance Junction To Ambient	$R_{_{\PhiJA}}$	-	-	60	°C/W

*CIRCUIT FOR PEAK OUTPUT VOLTAGE TEST

TYPICAL DIAC-TRIAC **FULL-WAVE PHASE CONTROL CIRCUIT**

